



Rare Earth Doped BaF₂ Crystals

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Introduction



- Undoped CsI crystal used for the Mu2e calorimeter has a fast scintillation at 310 nm with 30 ns decay time and survives an ionization dose up to 100 krad.
- BaF₂ crystal has a ultrafast scintillation at 220 nm with 0.5 ns decay time and a similar intensity as CsI, and may survive 100 Mrad. Its slow scintillation at 300 nm with 650 ns decay time, however, causes pileup in a high rate environment.
- Two approaches have been used to suppress the slow scintillation in BaF₂: (1) rare earth doping and/or (2) dedicated photodetector. Yttrium doping in BaF₂ crystals is found effective, promising a ultrafast calorimeter.
- Mass production capability of BaF₂ exists in industry:
 - BGRI (China), Incrom (Russia) and SICCAS (China);
 - Hellma (Germany).
- Reported today is the progress in rare earth doped BaF₂ crystals.



Some Fast Inorganic Scintillators



	LSO/LYSO	GSO	YSO	CsI	BaF ₂	CeF ₃	CeBr ₃	LaCl ₃	LaBr ₃	Plastic scintillator (BC 404) ^①
Density (g/cm ³)	7.4	6.71	4.44	4.51	4.89	6.16	5.23	3.86	5.29	1.03
Melting point (°C)	2050	1950	1980	621	1280	1460	722	858	783	70 [#]
Radiation Length (cm)	1.14	1.38	3.11	1.86	2.03	1.7	1.96	2.81	1.88	42.54
Molière Radius (cm)	2.07	2.23	2.93	3.57	3.1	2.41	2.97	3.71	2.85	9.59
Interaction Length (cm)	20.9	22.2	27.9	39.3	30.7	23.2	31.5	37.6	30.4	78.8
Z value	64.8	57.9	33.3	54	51.6	50.8	45.6	47.3	45.6	5.82
dE/dX (MeV/cm)	9.55	8.88	6.56	5.56	6.52	8.42	6.65	5.27	6.9	2.02
Emission Peak ^a (nm)	420	430	420	310	300 220	340	371	335	356	408
Refractive Index ^b	1.82	1.85	1.8	1.95	1.5	1.62	1.9	1.9	1.9	1.58
Relative Light Yield ^{a,c}	100	45	76	3.6 1.1	42 4.1	8.6	99	15 49	153	35
Decay Time ^a (ns)	40	73	60	30 6	650 0.5	30	17	570 24	20	1.8
d(LY)/dT ^d (%/°C)	-0.2	-0.4	-0.1	-1.4	-1.9 0.1	~0	-0.1	0.1	0.2	~0

a. Top line: slow component, bottom line: fast component.

b. At the wavelength of the emission maximum.

c. Relative light yield normalized to the light yield of LSO

d. At room temperature (20°C)

#. Softening point

1. <http://www.detectors.saint-gobain.com/Plastic-Scintillator.aspx>

http://pdg.lbl.gov/2008/AtomicNuclearProperties/HTML_PAGES/216.html

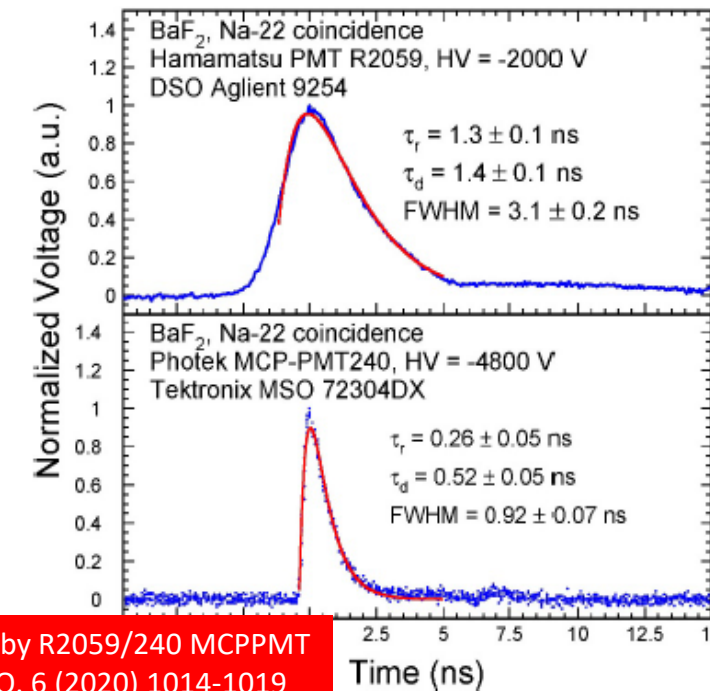
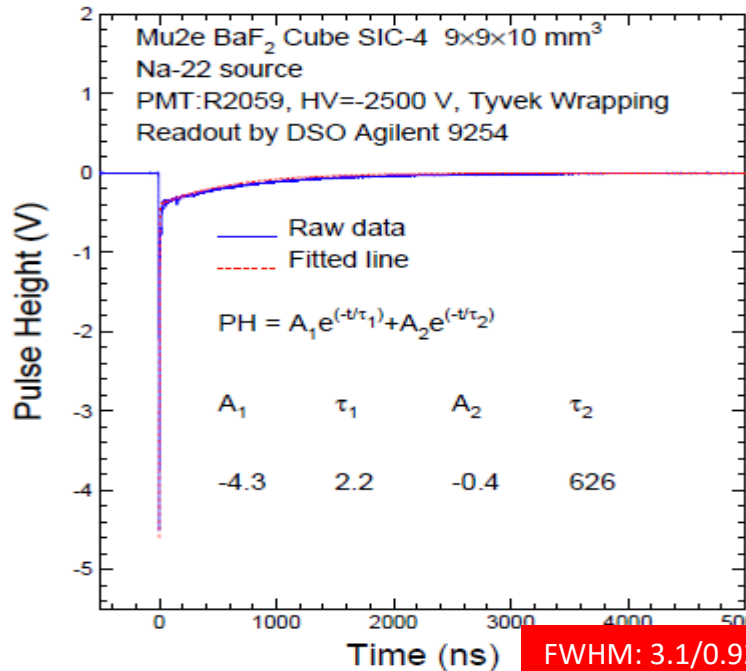
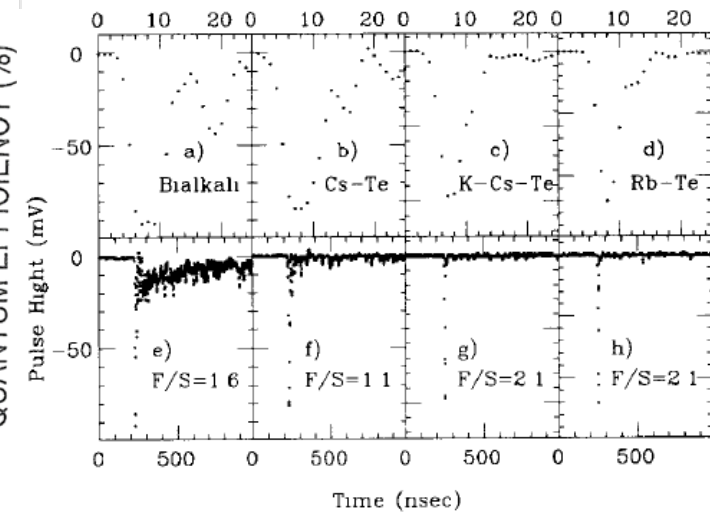
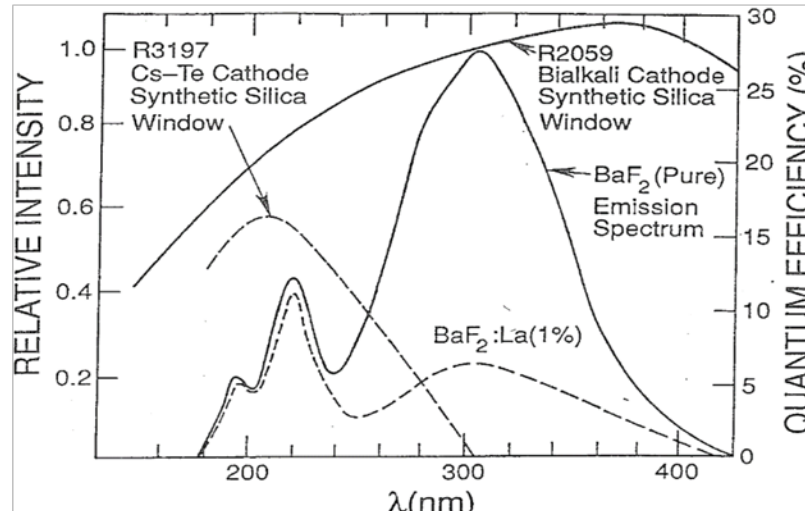
The 0.5 ns scintillation in BaF₂ promises a ultrafast crystal calorimeter to face the challenge of high event rate expected by Mu2e-II



Ultrafast and Slow Light from BaF₂

BaF₂ has a ultrafast scintillation component @ 220 nm with 0.5 ns decay time and an intensity similar to undoped CsI. It has also a factor of 5 larger slow component @ 300 nm with 300 ns decay time.

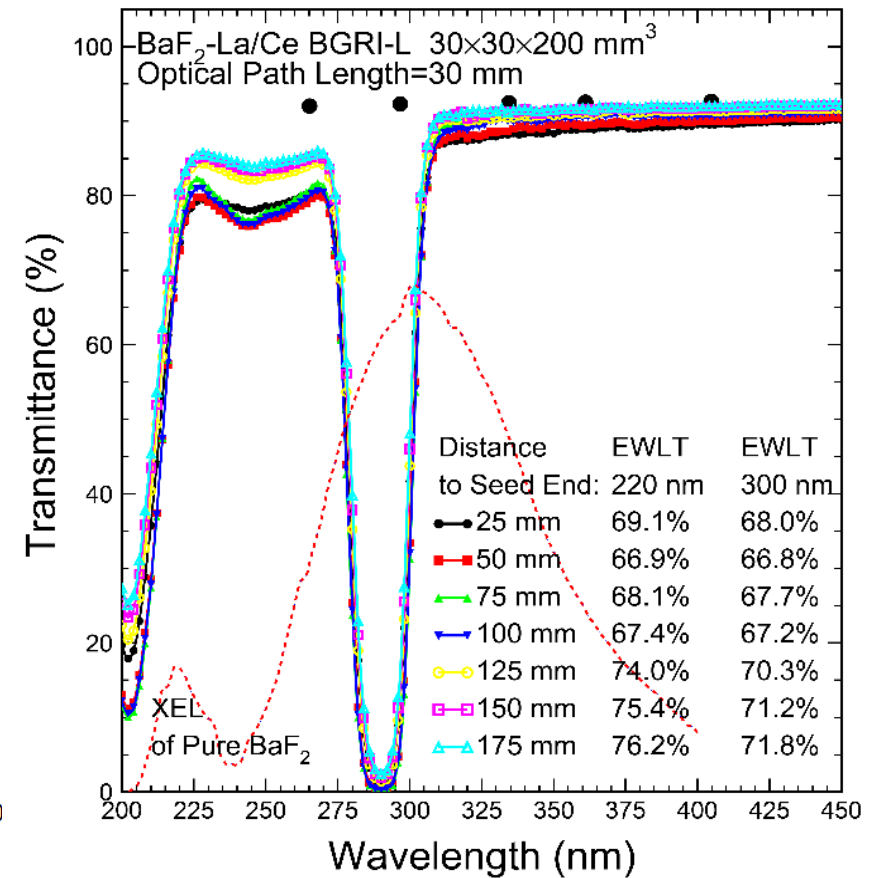
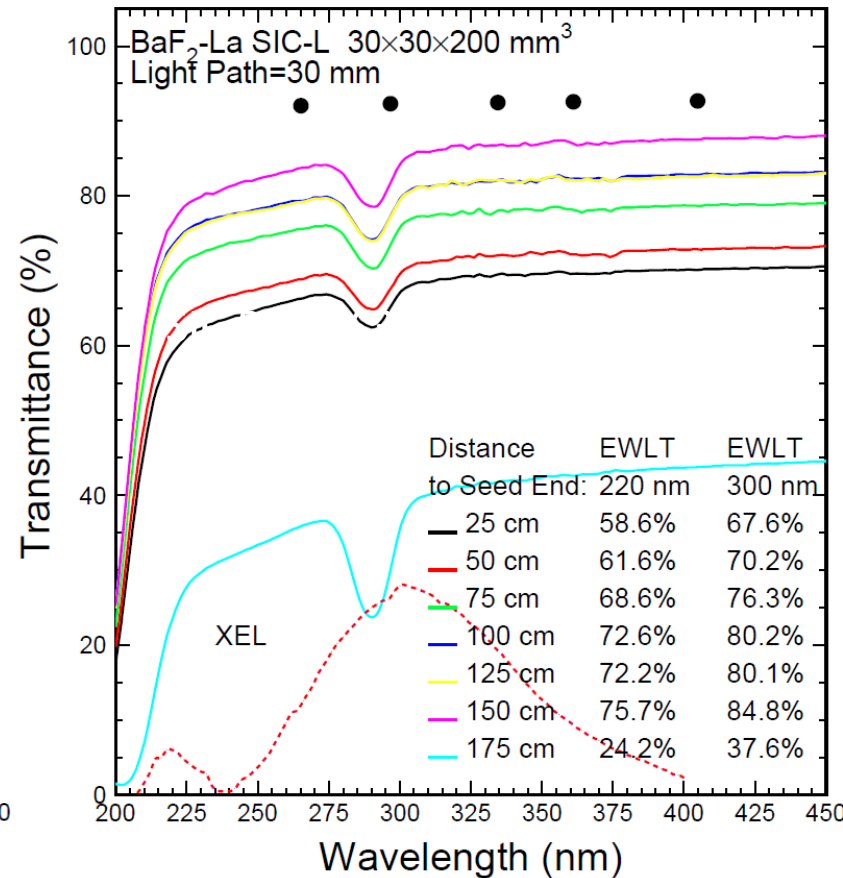
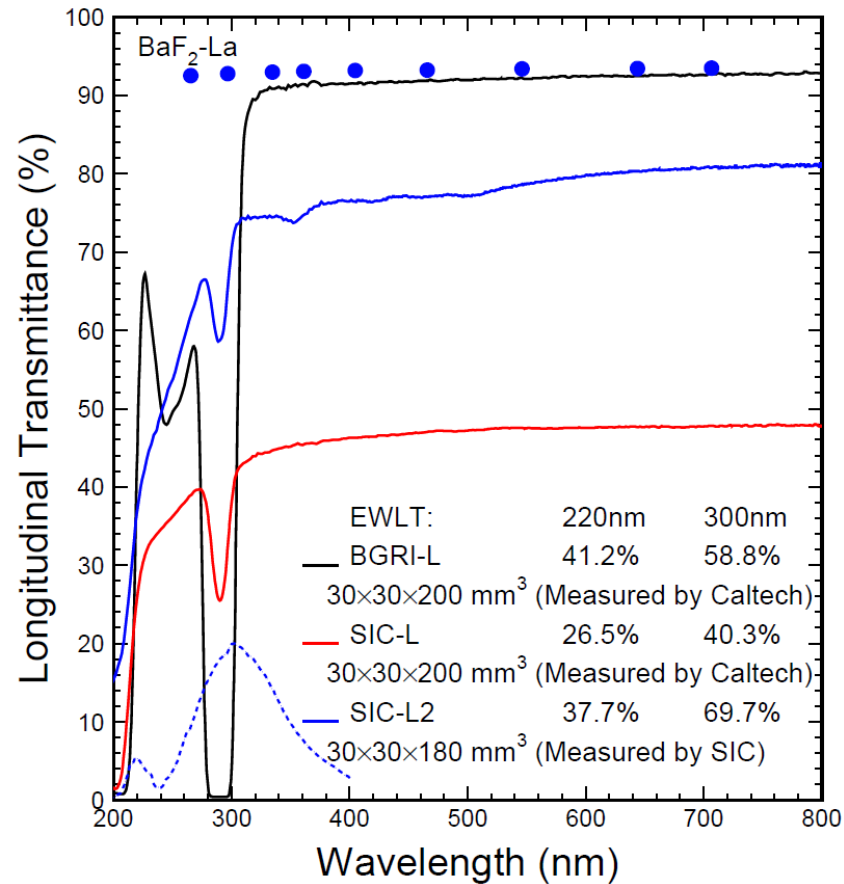
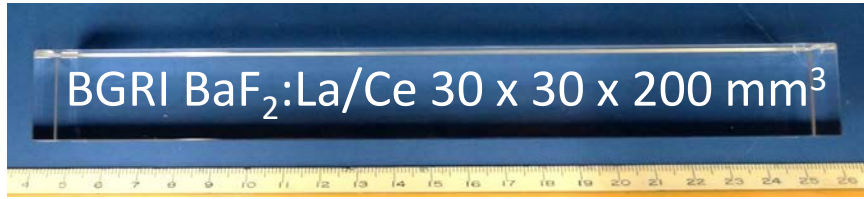
Slow suppression may be achieved by rare earth (Y, La and Ce) doping, and/or solar-blind photo-detectors, e.g. Cs-Te, K-Cs-Te and Rb-Te cathode
NIMA 340 (1994) 442-457



FWHM: 3.1/0.92 ns by R2059/240 MCPPMT
IEEE TNS NS 67, NO. 6 (2020) 1014-1019



Transmittance of BaF₂:La and BaF₂:La/Ce



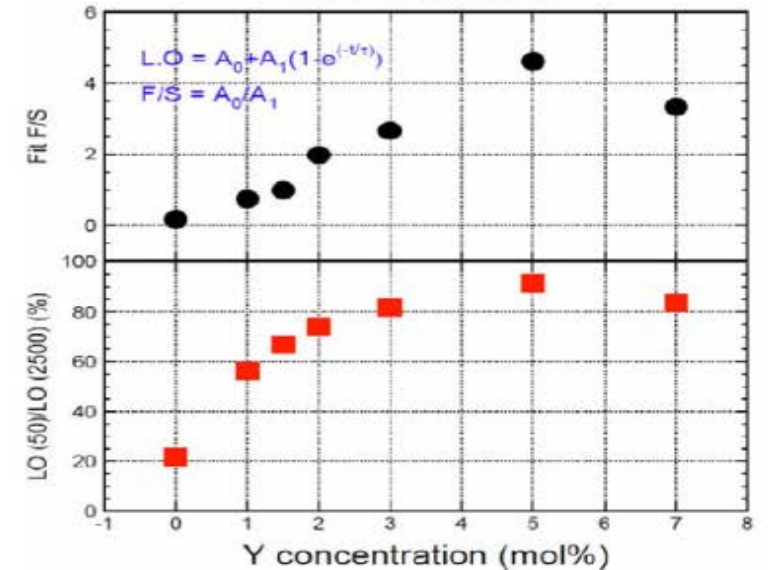
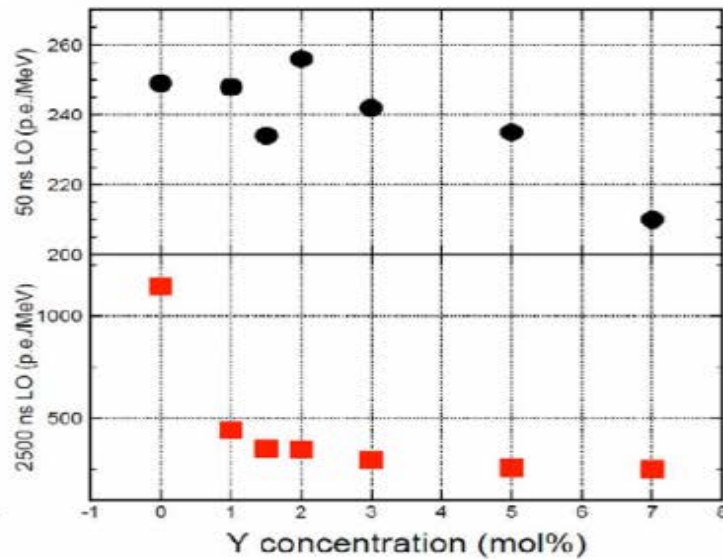
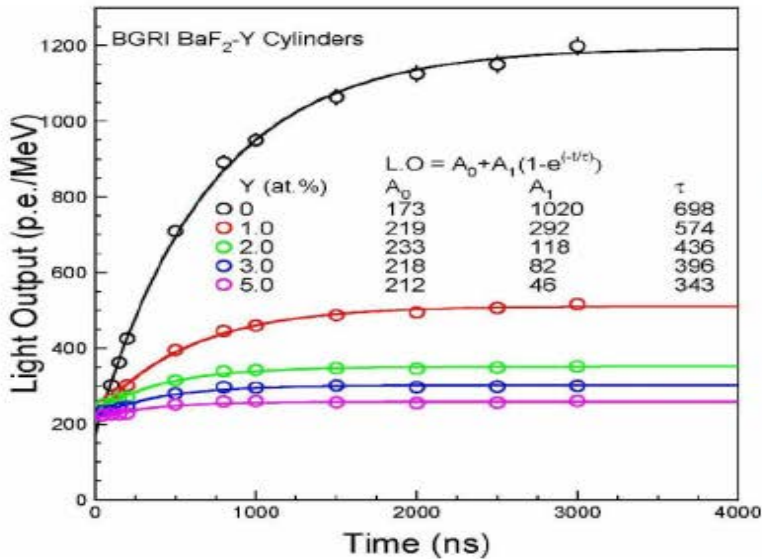
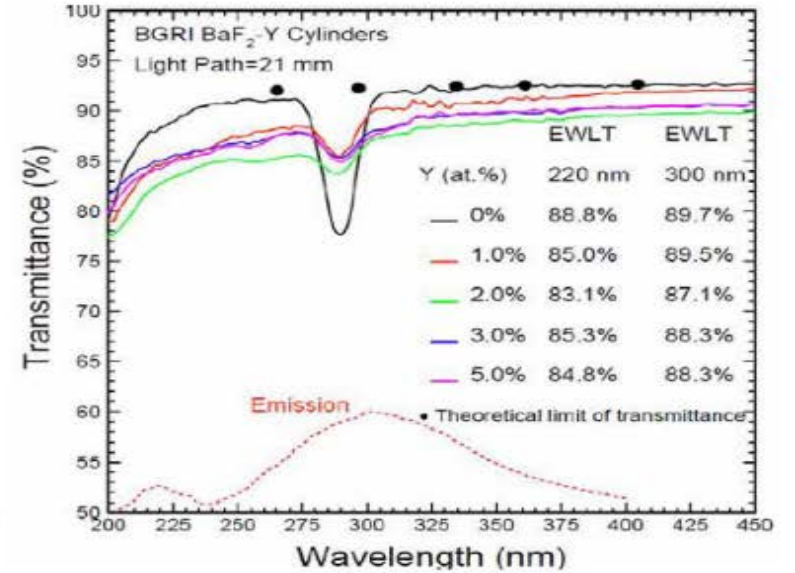
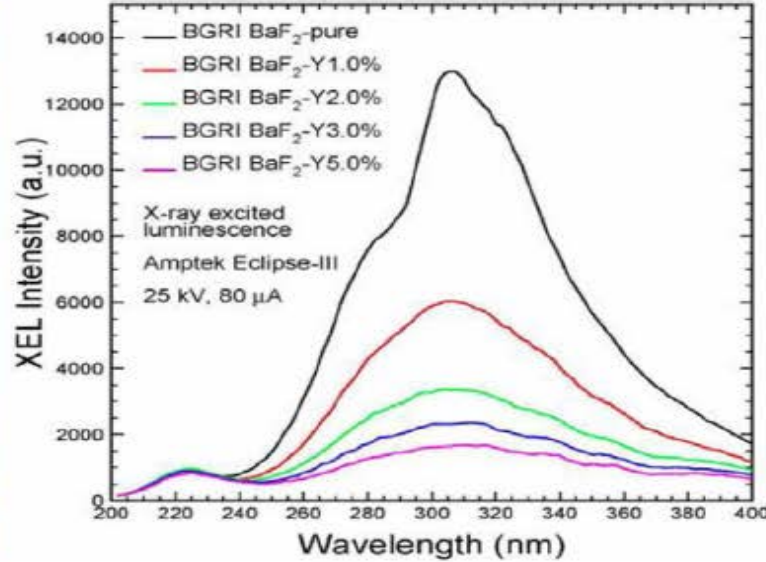
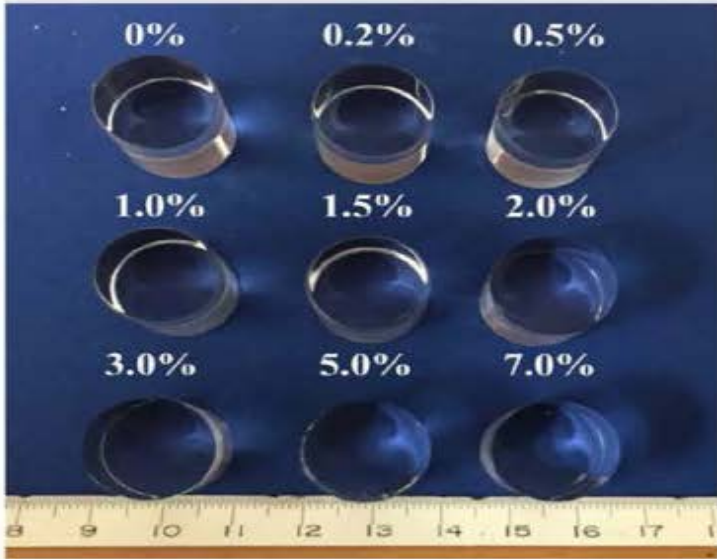
Absorptions observed in La and La/Ce doped BaF₂ IEEE TNS 66 (2019) 506-518



Yttrium Doped Small BaF₂ Samples



Increased F/S ratio observed in BGRI BaF₂:Y crystals, Proc. SPIE 10392 (2017)

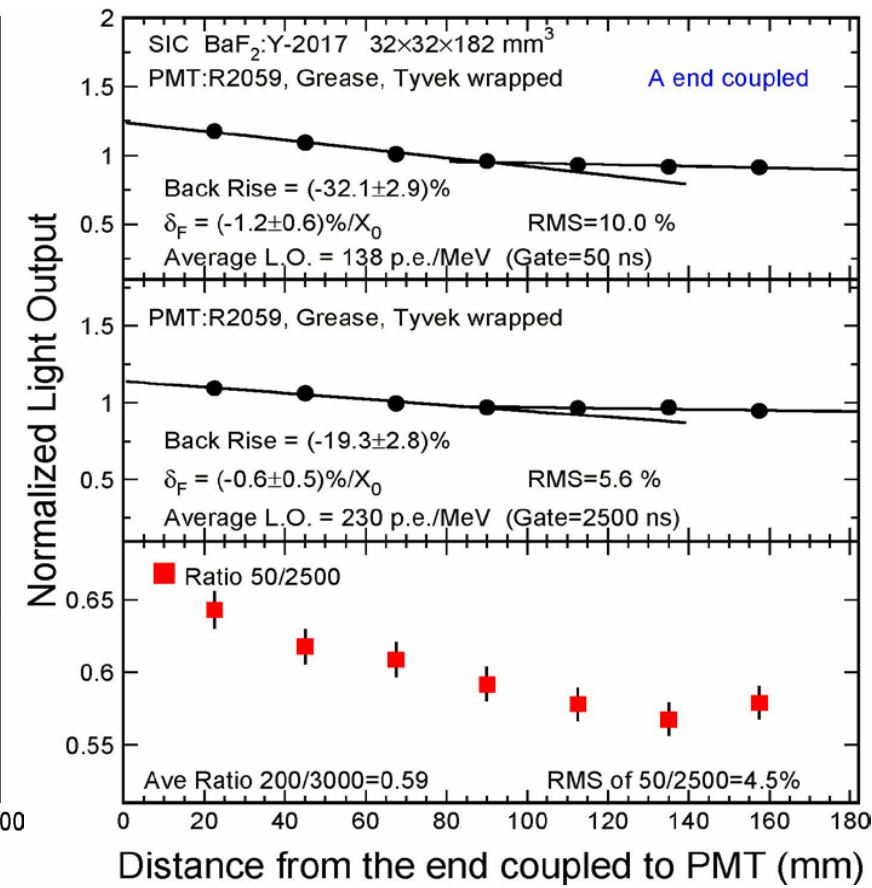
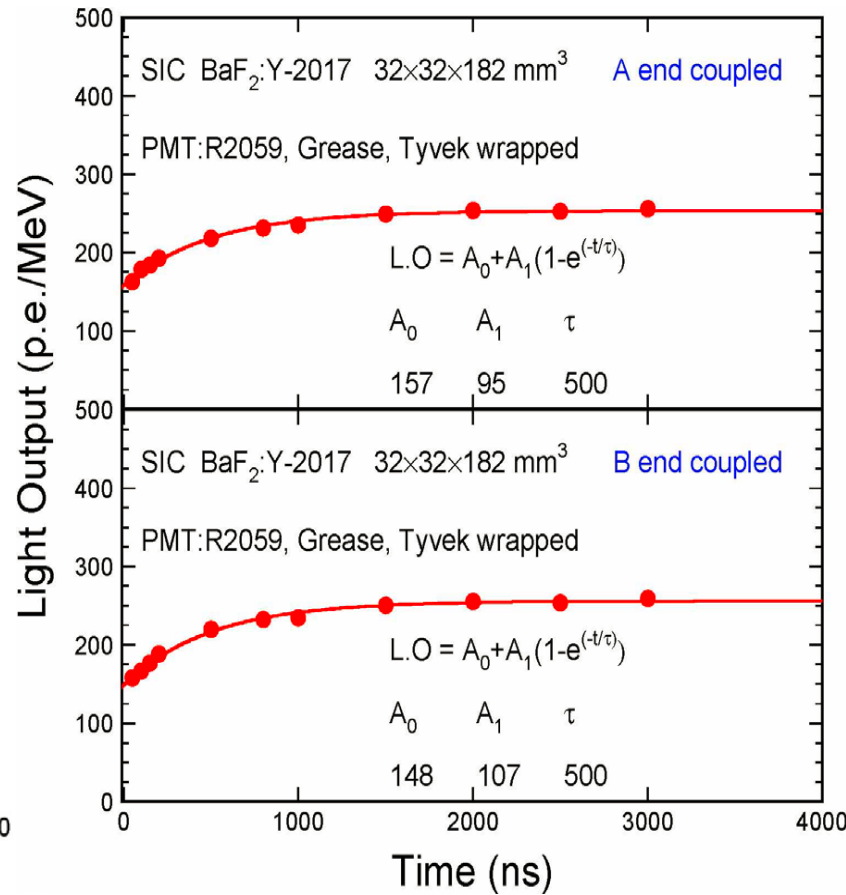
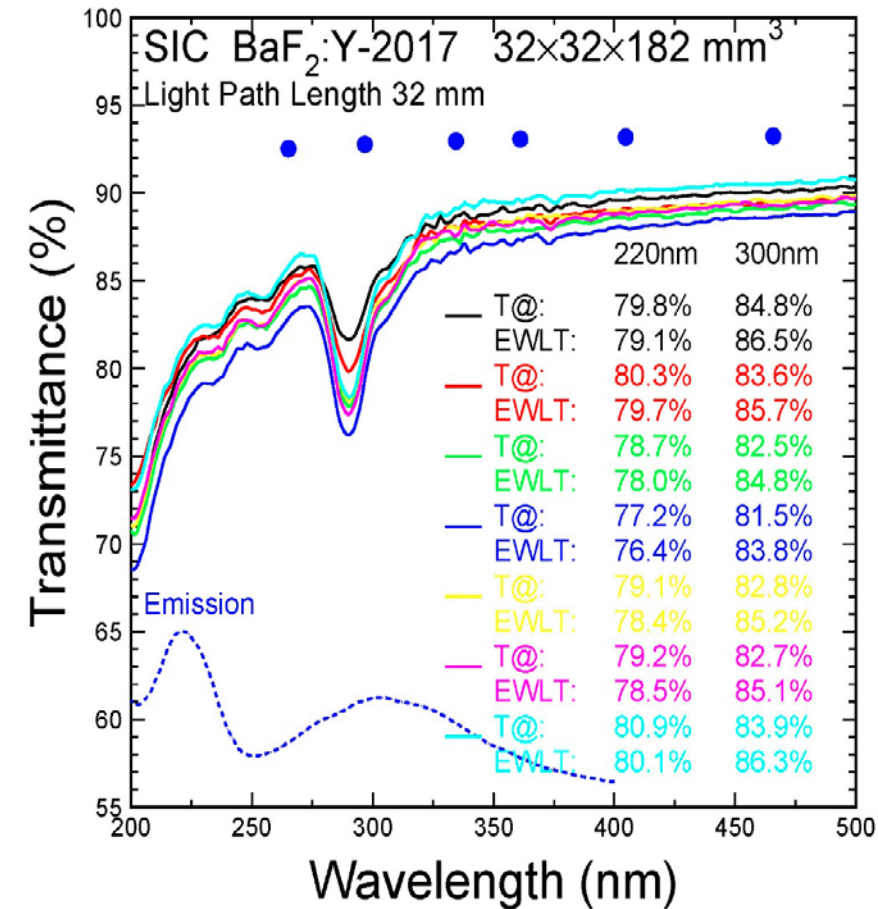




SIC BaF₂:Y-2017

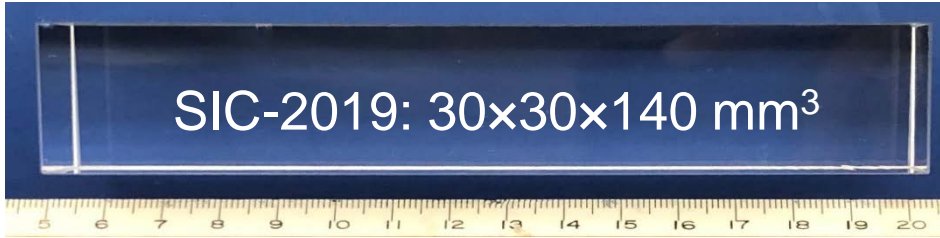


F: 150 p.e./MeV, F/S: 1.5
F/T LRU: 10%/6%, δ_F : -1.2%/X₀

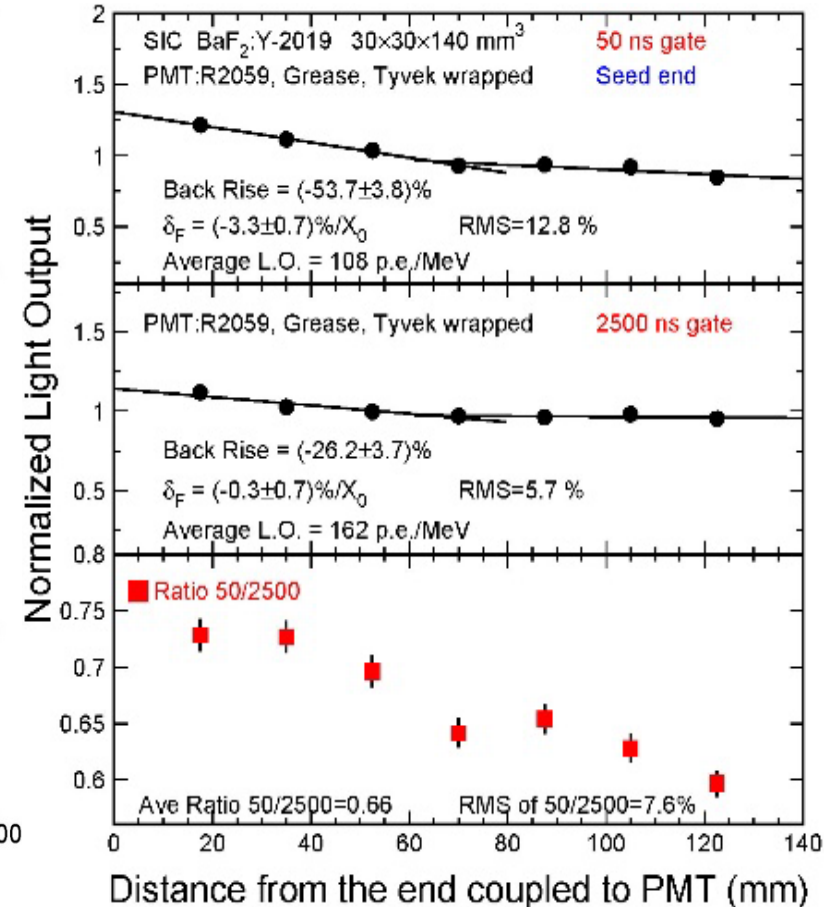
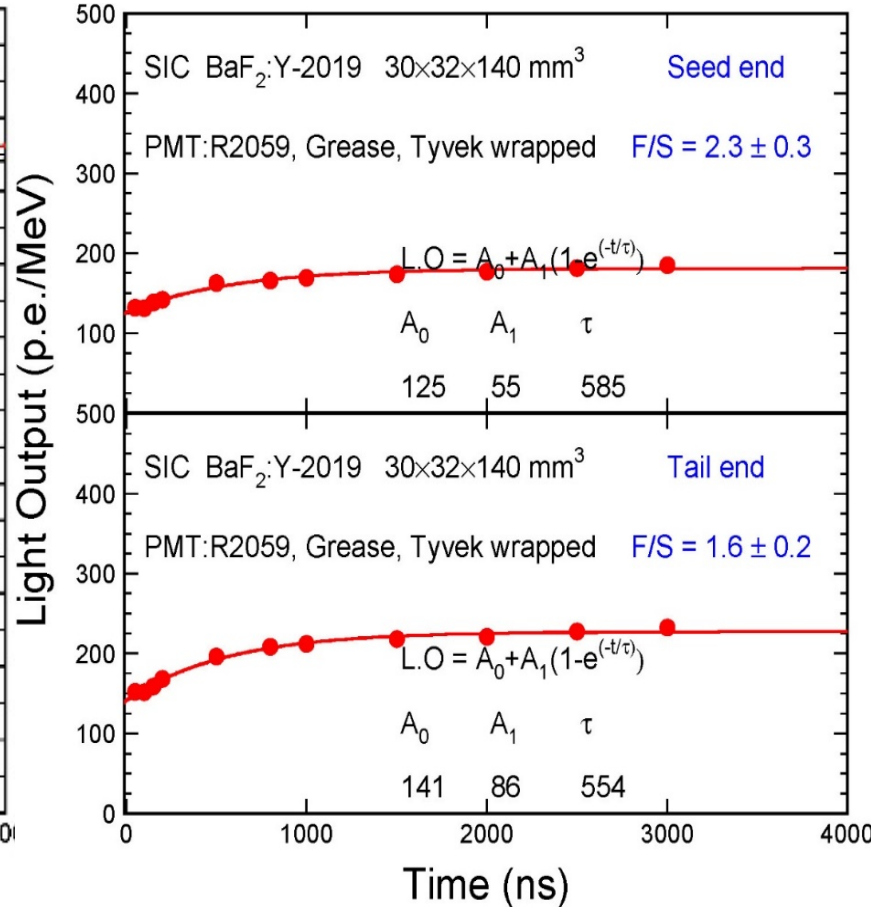
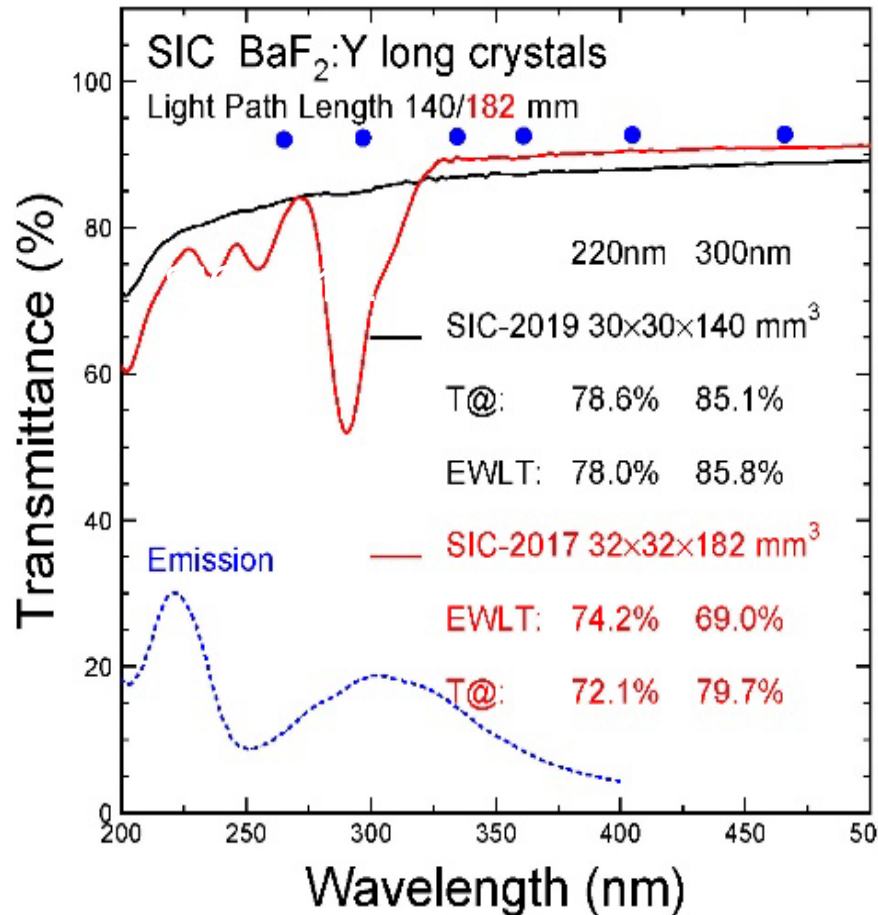




SIC BaF₂:Y-2019

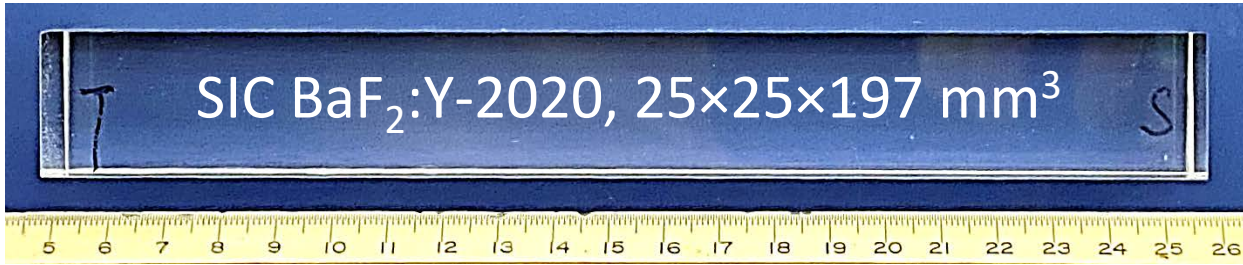


F: 130 p.e./MeV, F/S: 2
 F/T LRU: 13%/6% %, δ_F : -3.3%/X₀

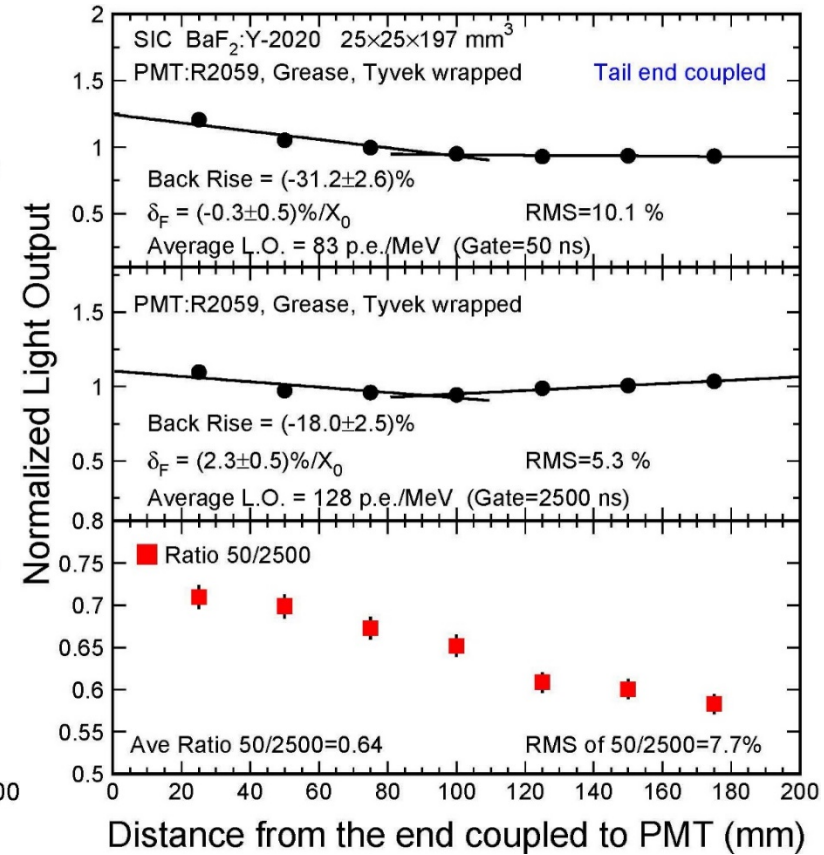
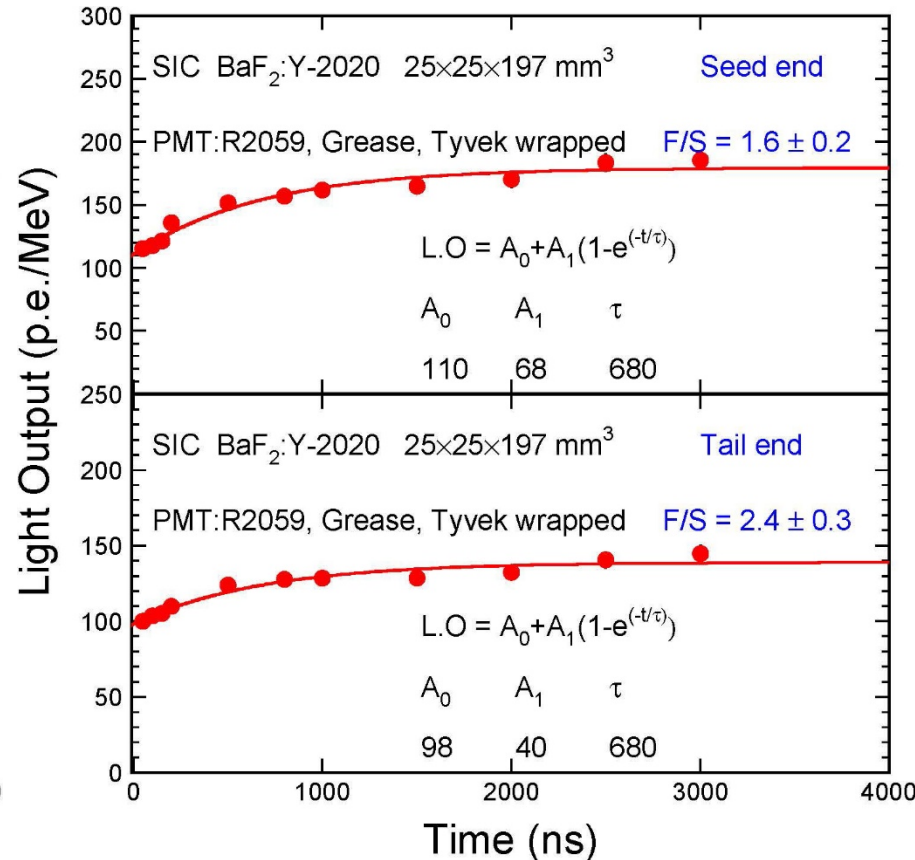
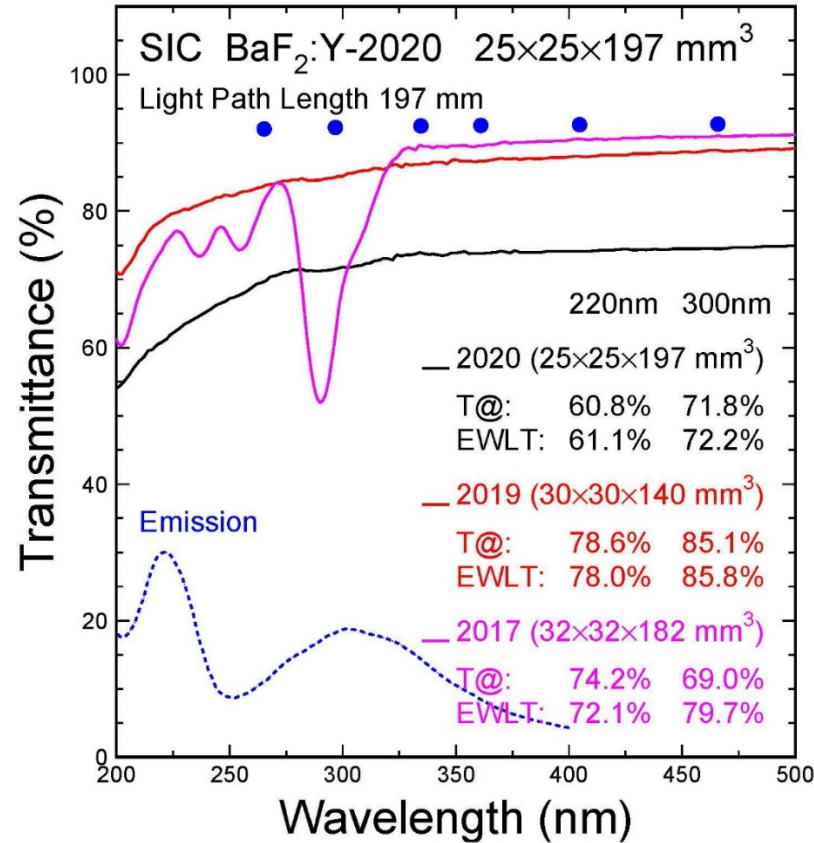




SIC BaF₂:Y-2020



F: 100 p.e./MeV, F/S: 2
F/T LRU: 10%/5% %, δ_F : -0.3%/X₀

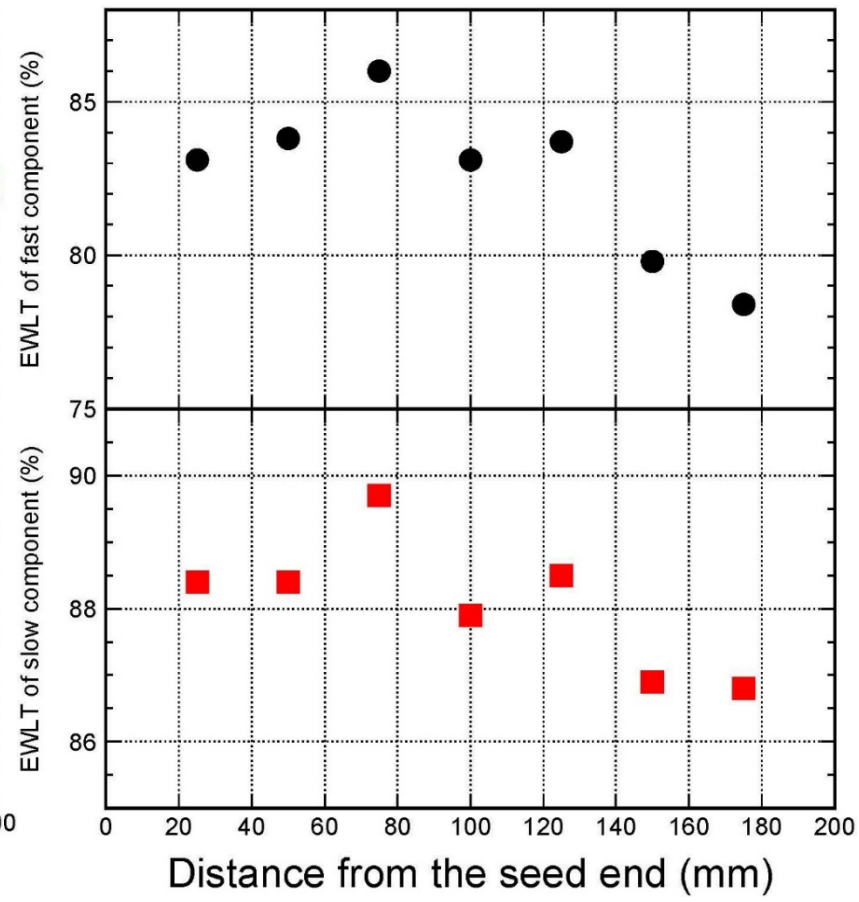
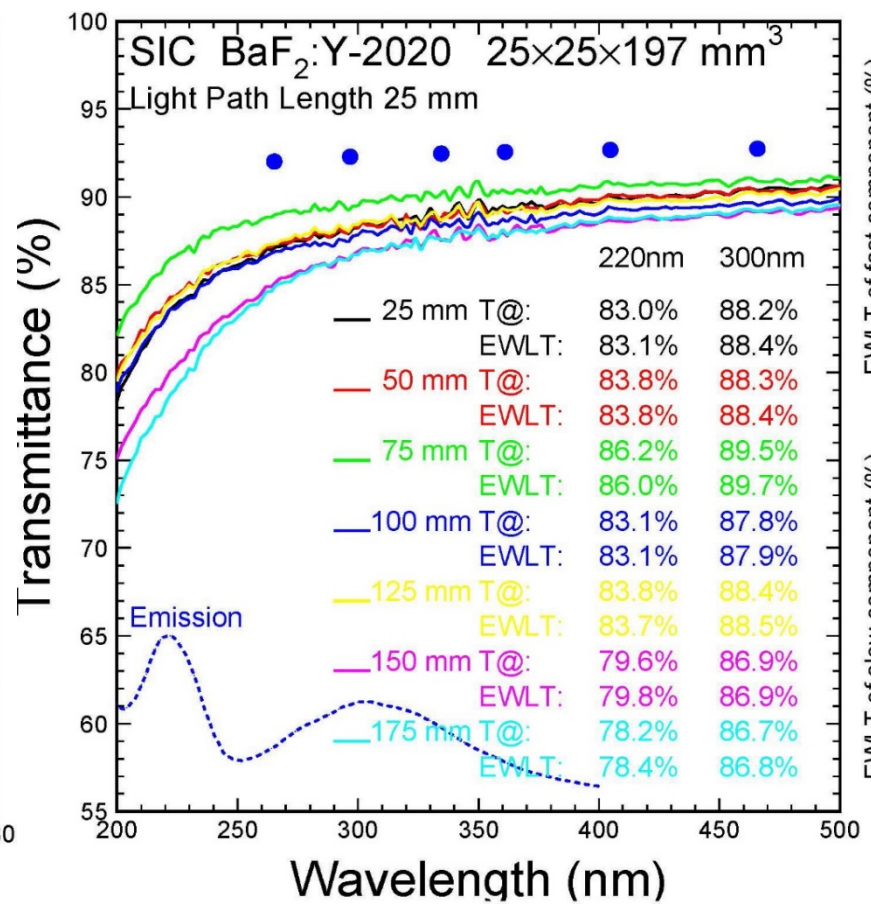
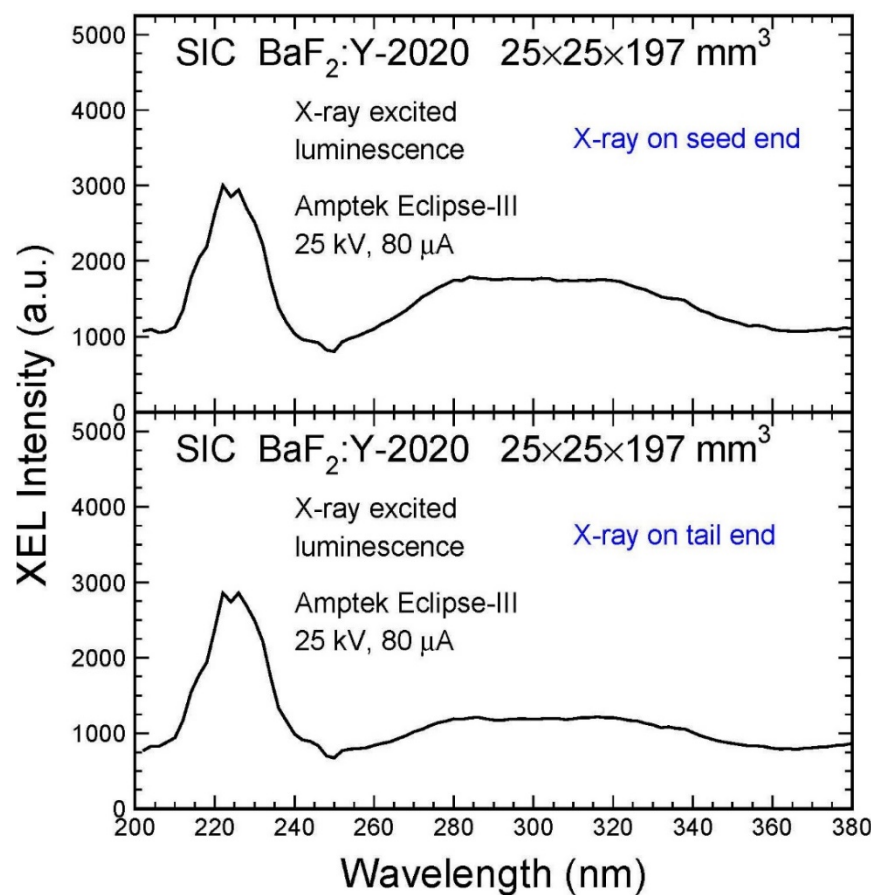




SIC BaF₂:Y-2020: Transverse T



A variation of slow emission intensity and more scattering centers starting from 15 cm from the seed





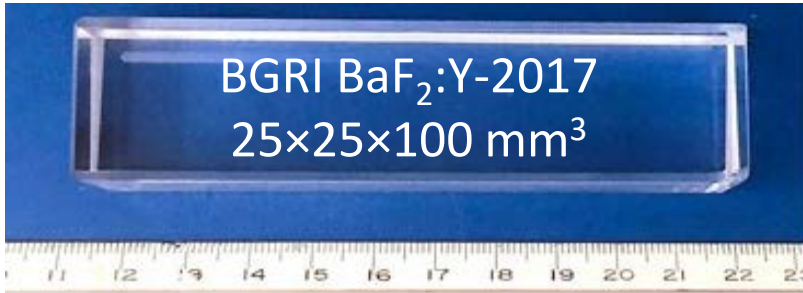
Summary: SIC BaF₂:Y Long Crystals

Achievable: LO_F > 100 p.e./MeV, F/S > 2, 10% LRU and |δ_F| < 3%/X₀

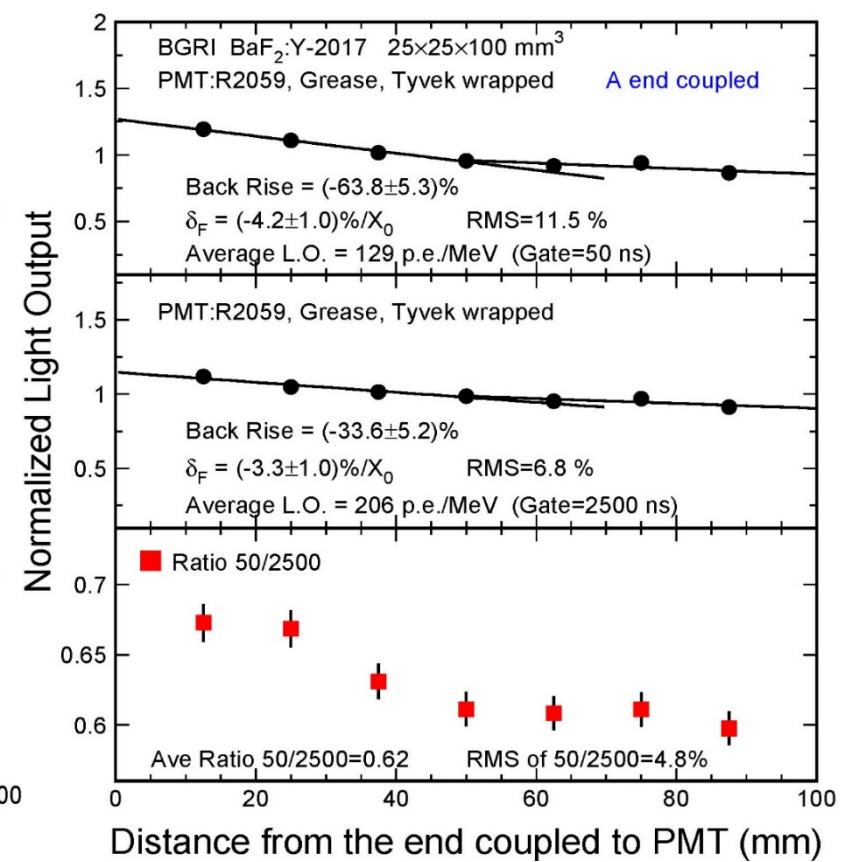
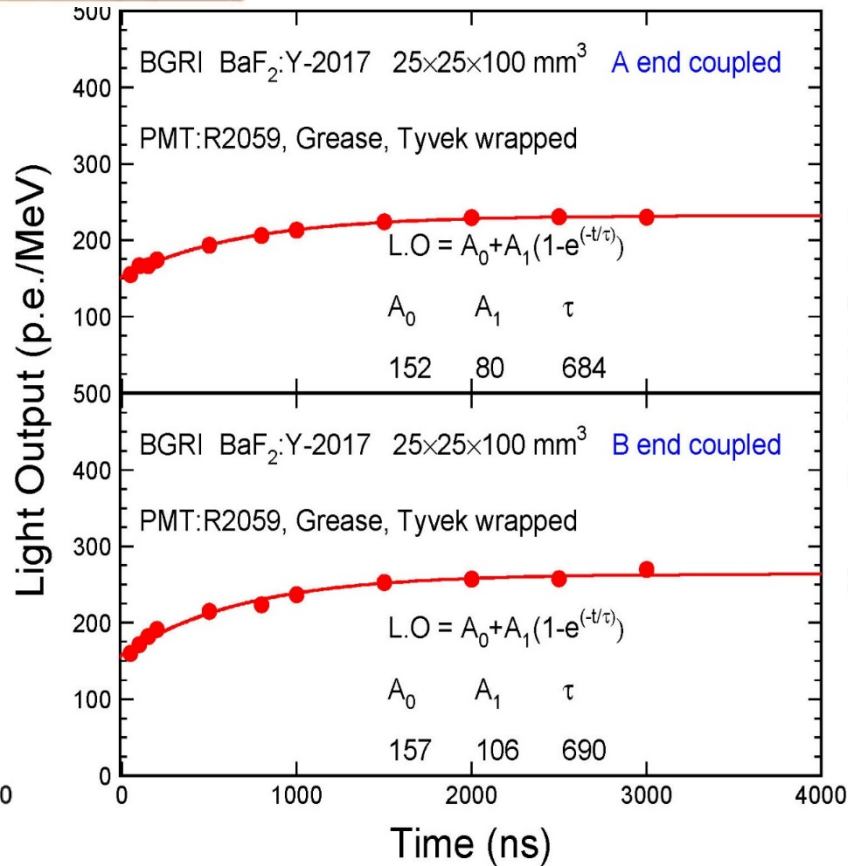
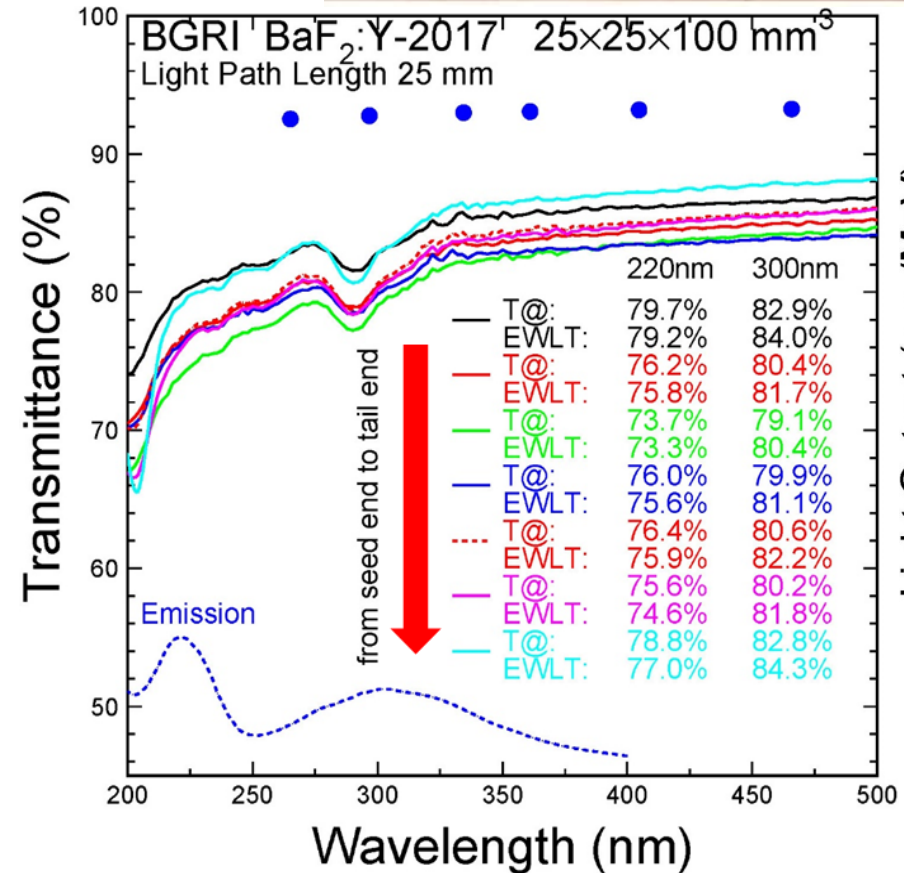
ID	Dimension (mm ³)	EWLT Fast (%)	EWLT Slow (%)	Coupling end	Basic Scintillation Performance ²² Na source @ 1/8 length from the coupling end					Light Response Uniformity		
					50 ns LO (p.e./MeV)	2500 ns LO (p.e./MeV)	LO(50)/LO(2500)	F	F/S	50 ns LO	2500 ns LO	LO(50)/LO(2500)
SIC BaF ₂ :Y-2017	32x32x182	72.1	79.7	A	162	253	0.64	157	1.7	138 (10.0%)	230 (5.6%)	0.59 (4.5%)
				B	158	254	0.62	148	1.4	116 (19.1%)	200 (16.4%)	0.57 (3.7%)
SIC BaF ₂ :Y-2019	30x30x140	78.0	85.8	A	132	181	0.73	125	2.3	108 (12.8%)	162 (5.7%)	0.66 (7.6%)
				B	152	227	0.67	141	1.6	117 (15.6%)	177 (14.9%)	0.66 (1.5%)
SIC BaF ₂ :Y-2020	25x25x197	61.1	72.2	Seed	115	183	0.63	110	1.6	88 (17.7%)	136 (20.5%)	0.64 (2.8%)
				Tail	100	141	0.71	98	2.4	83 (10.1%)	128 (5.3%)	0.64 (7.7%)



BGRI BaF₂:Y-2017

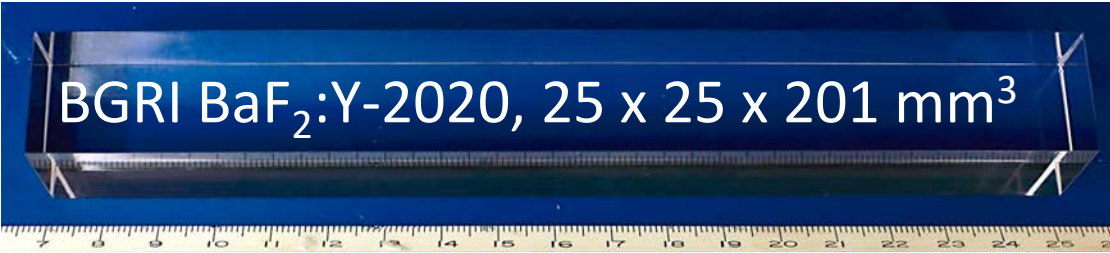


F: 150 p.e./MeV, F/S: 1.5
F/T LRU: 12%/7% %, δ_F : -4.2%/X₀

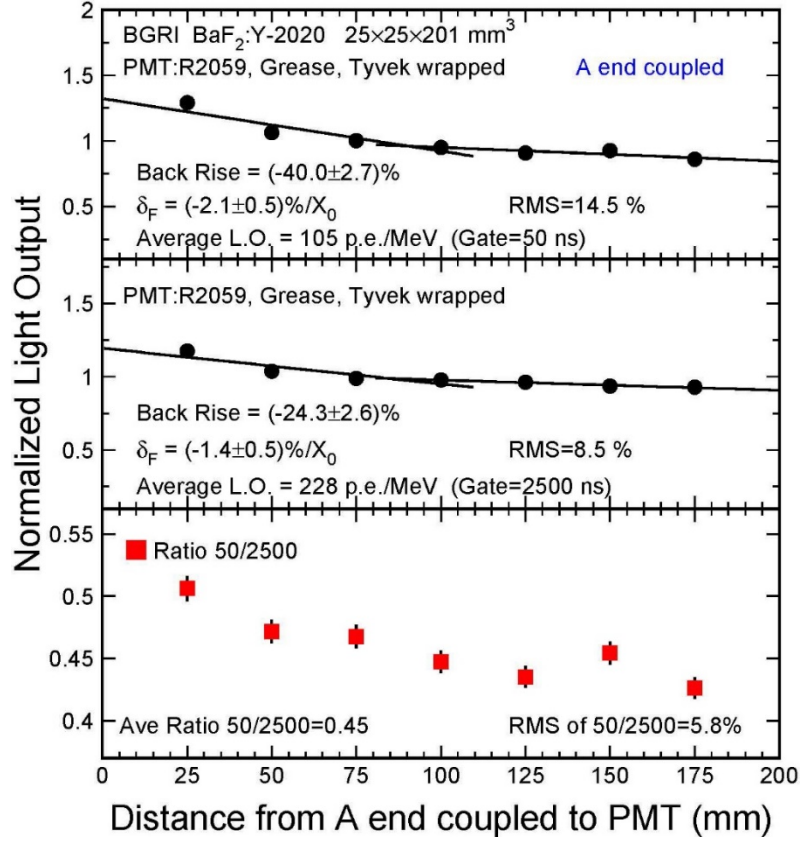
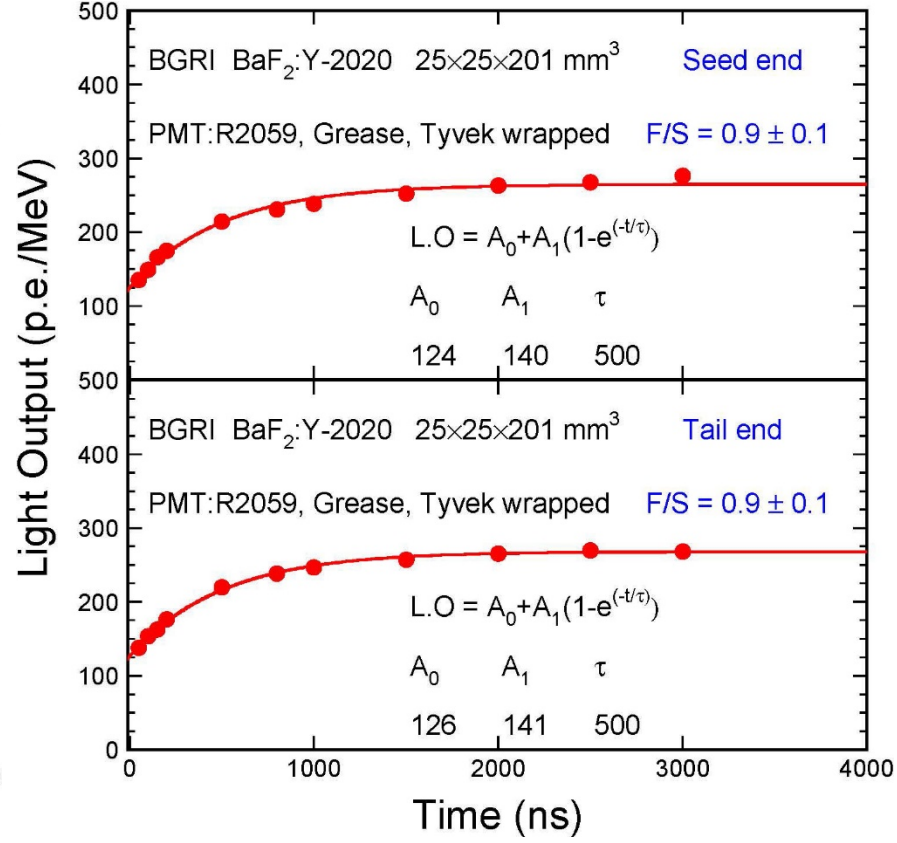
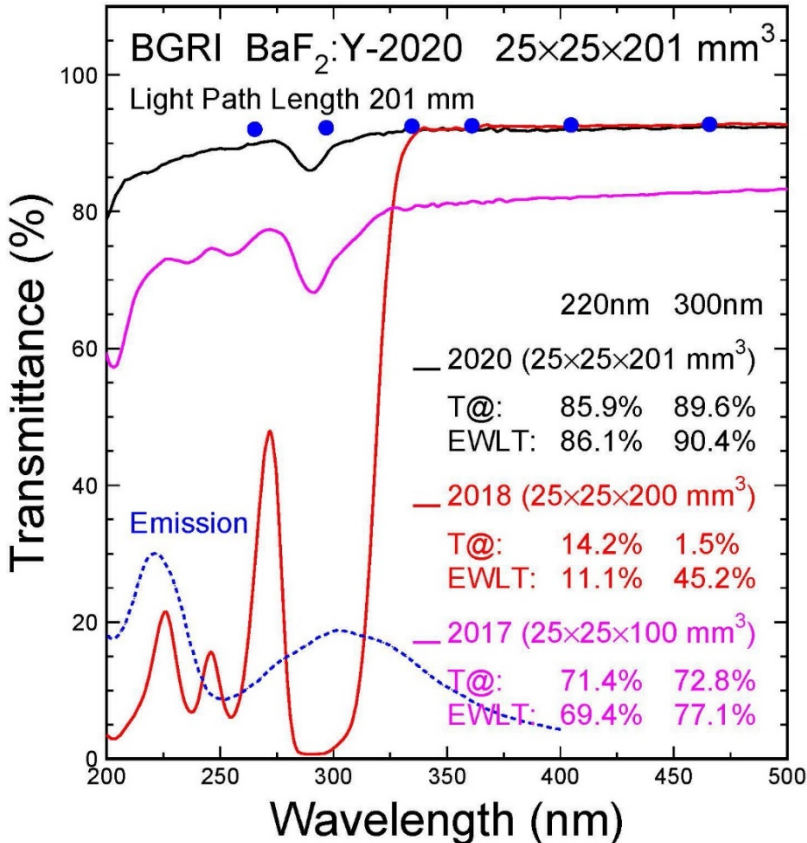




BGRI BaF₂:Y-2020



F: 125 p.e./MeV, F/S: 0.9
 F/T LRU: 15%/9% %, δ_F : -2.1%/X₀

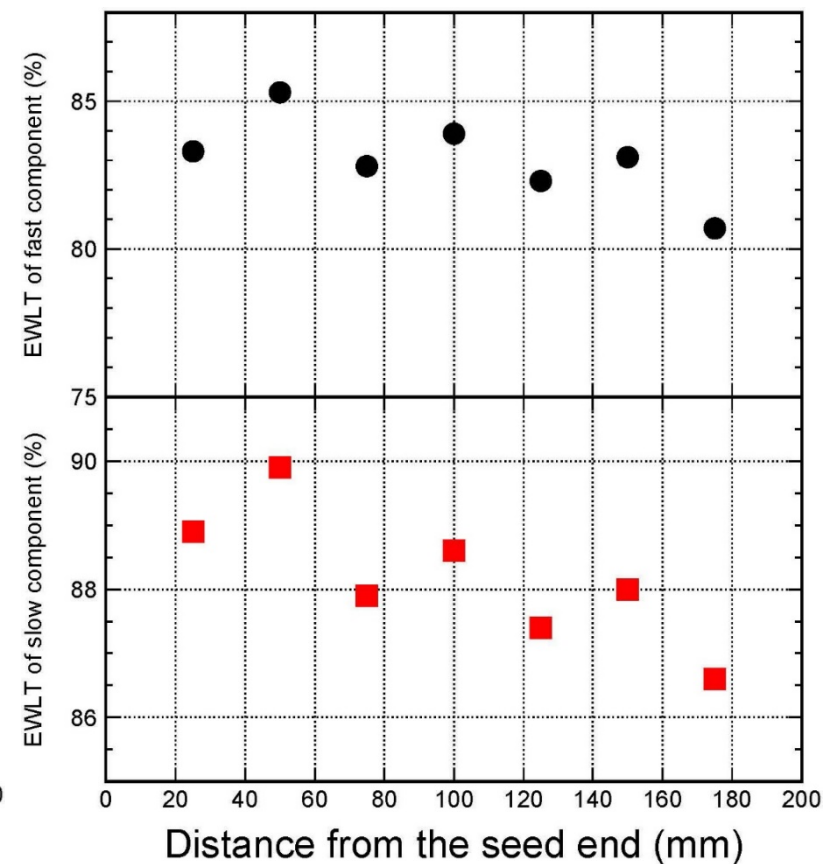
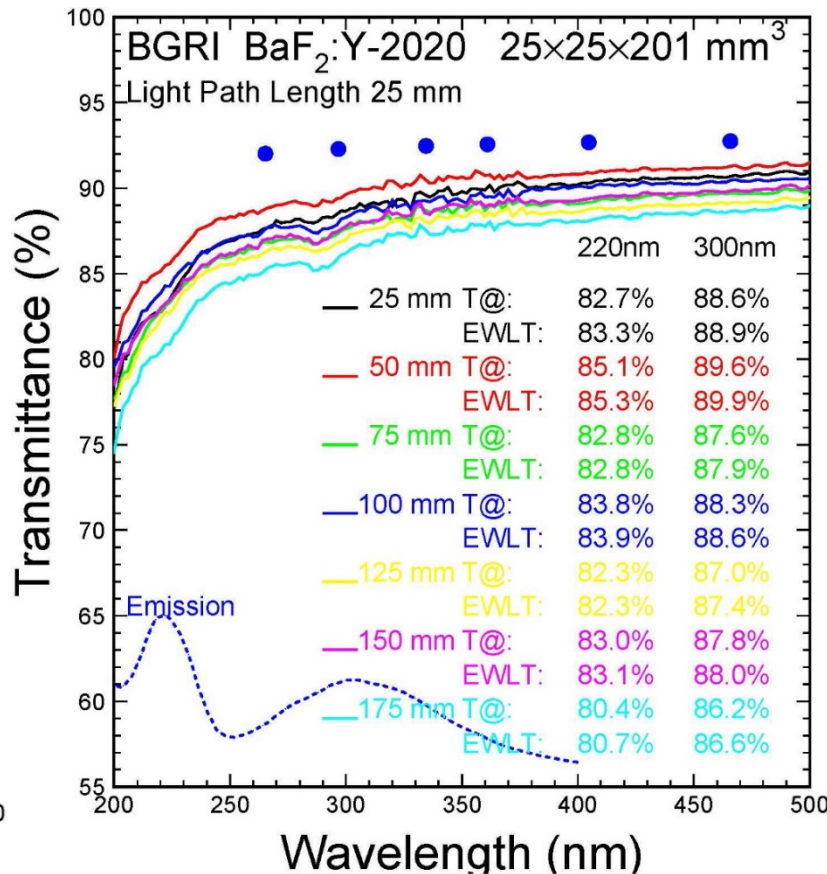
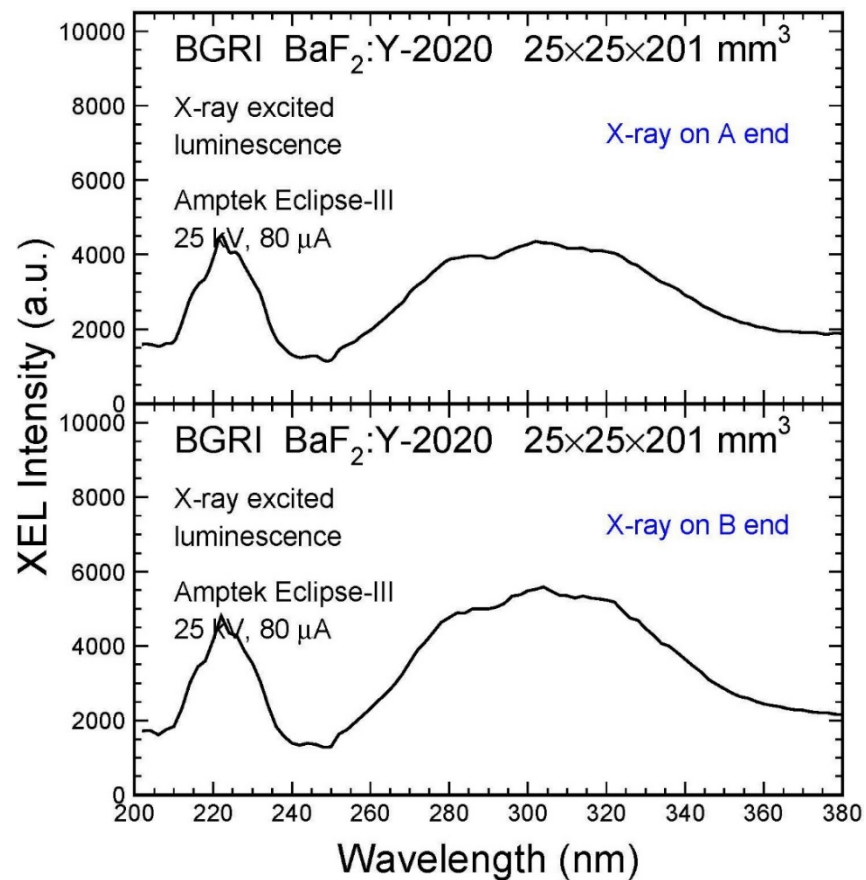




BGRI BaF₂:Y-2020: Transverse T



A variation of slow emission intensity and good optical quality along the crystal length





Summary: BGRI BaF₂:Y Long Crystals



Achievable: LO_F>100 p.e./MeV, F/S>2, 10% LRU and |δ_F|<3%/X₀

ID	Dimension (mm ³)	EWLT Fast (%)	EWLT Slow (%)	Coupling end	Basic Scintillation Performance ²² Na Source @ 1/8 length from the coupling end					Light Response Uniformity		
					50 ns LO (p.e./MeV)	2500 ns LO (p.e./MeV)	LO(50)/LO(2500)	F	F/S	50 ns LO	2500 ns LO	LO(50)/LO(2500)
BGRI BaF ₂ :Y-2017	25x25x100	69.4	77.1	A	155	231	0.67	152	1.9	129 (11.5%)	206 (6.8%)	0.62 (4.8%)
				B	160	258	0.62	157	1.5	129 (15.4%)	214 (13.7%)	0.60 (2.1%)
BGRI BaF ₂ :Y-2018*	25x25x200	11.1	45.2	A	133	317	0.42	203	NA	83 (30.6%)	229 (20.4%)	0.35 (9.4%)
				B	133	265	0.52	159	NA	89 (26.4%)	228 (8.7%)	0.38 (17.2%)
BGRI BaF ₂ :Y-2020	25x25x201	61.1	72.2	A	135	268	0.50	124	0.9	105 (14.5%)	228 (8.5%)	0.45 (5.8%)
				B	138	270	0.51	126	0.9	106 (17.1%)	221 (14.7%)	0.47 (3.1%)

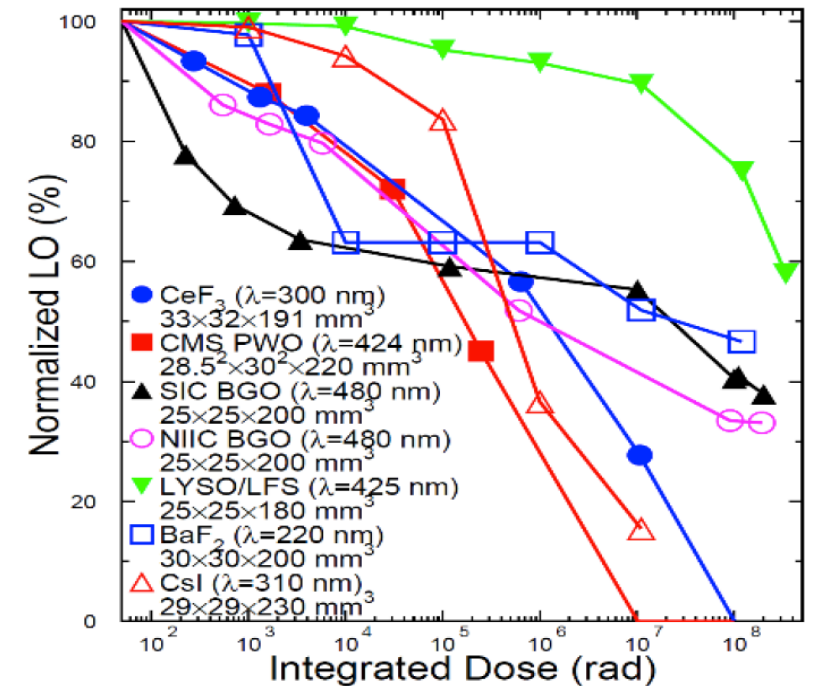
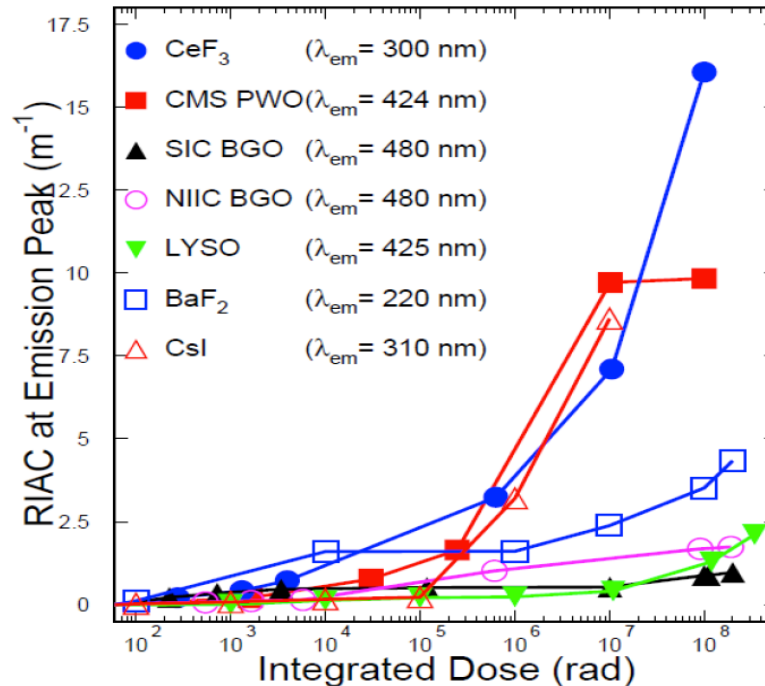
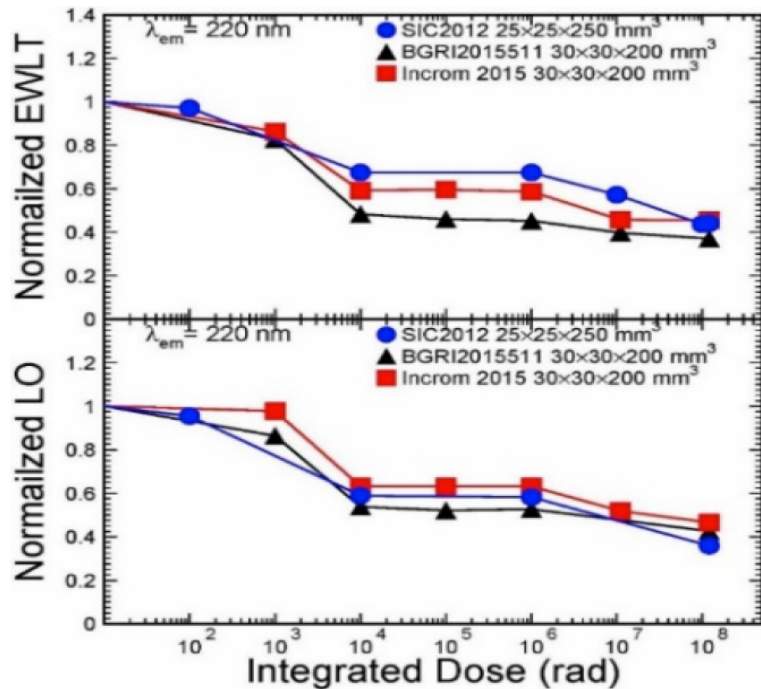
*CeF₃: Only one component with 30~50 ns decay time is observed, but no ultrafast component



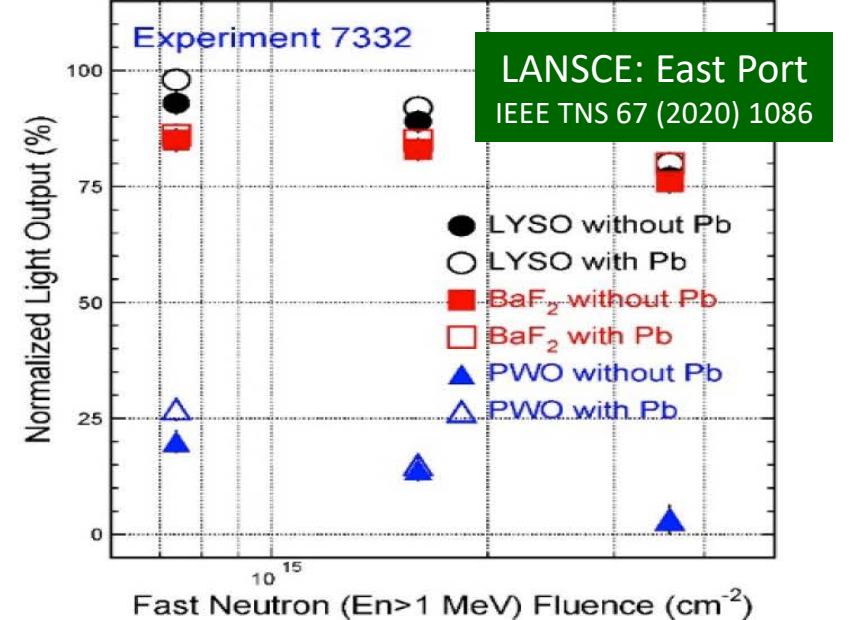
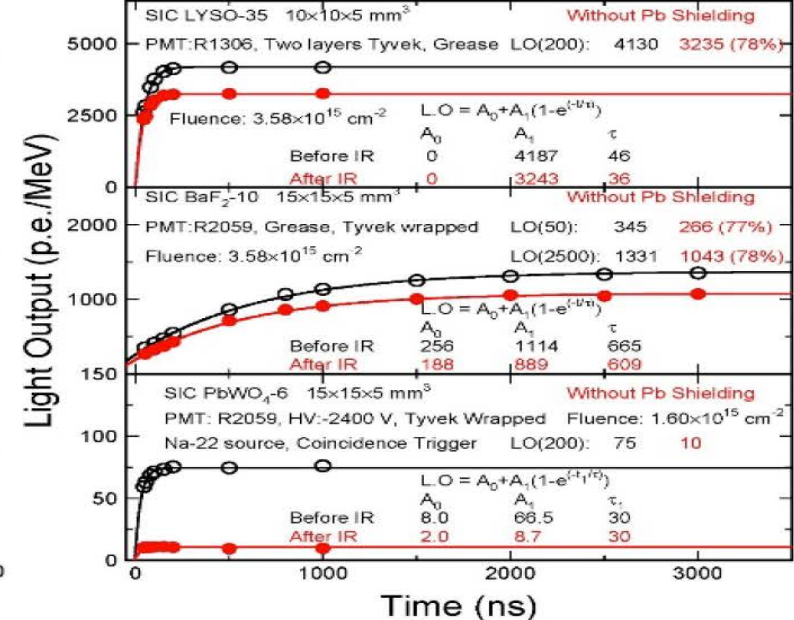
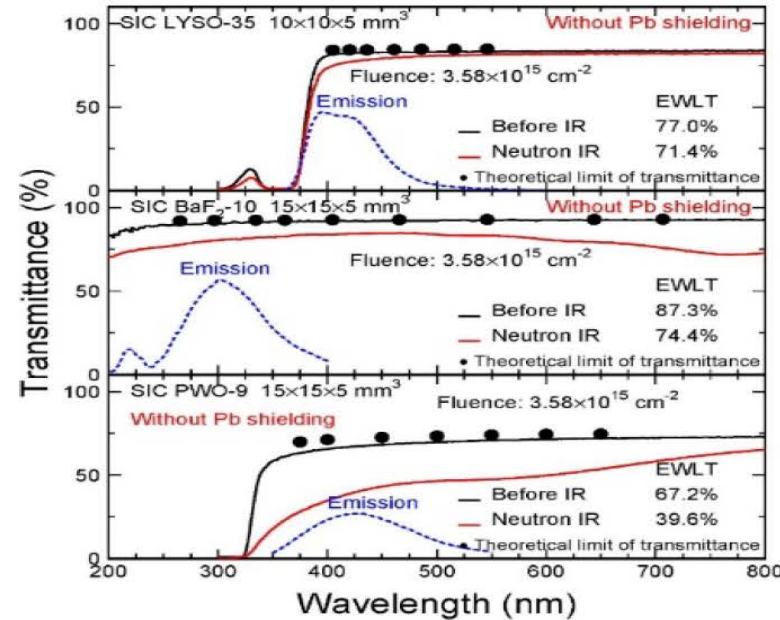
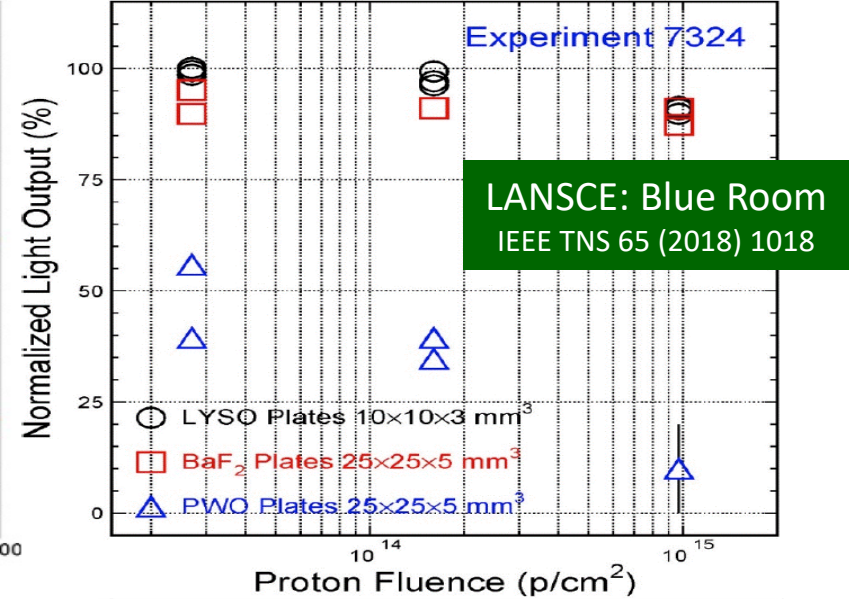
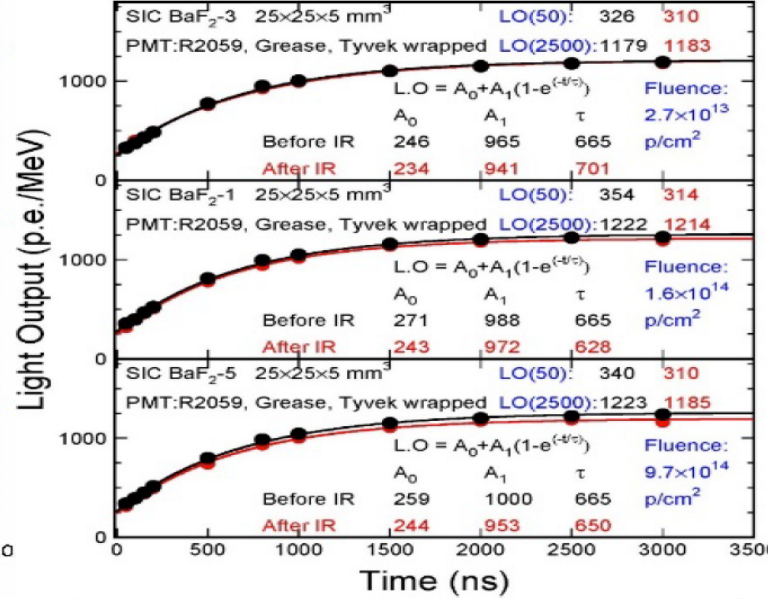
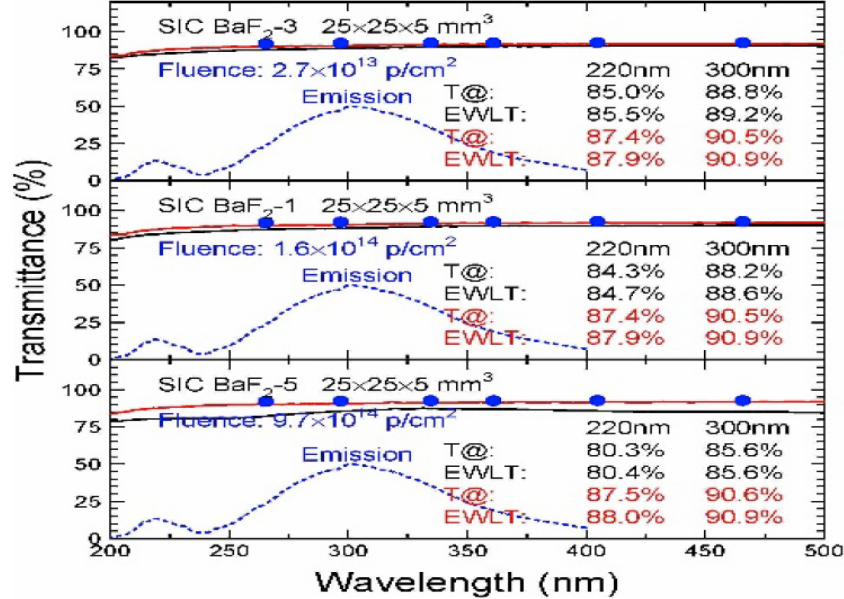
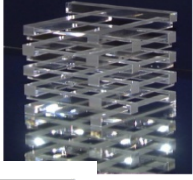
γ -Ray Induced Damage in Large BaF₂



20 cm long BaF₂ shows ~50% light output loss after 120 Mrad, indicating good radiation resistance against ionization dose. IEEE TNS 63 (2016) 612-619



Proton and Neutron Induced Damage in BaF₂





Summary



- ❑ BaF₂ crystals provide ultrafast light with 0.5 ns decay time. Yttrium doping increases the F/S ratio while maintaining the ultrafast light intensity. With sub-ns pulse width BaF₂:Y promises a ultrafast calorimeter.
- ❑ 20 cm long BaF₂ crystals show ~50% LO loss after 120 Mrad. 5 mm thick BaF₂ plates show less than 20% LO after 1×10^{15} p/cm² or 3.6×10^{15} n_{eq}/cm², indicating that BaF₂ of short light path may be used in a severe radiation environment.
- ❑ Achievable performance of 20 cm long BaF₂:Y crystals: LO_F>100 p.e./MeV, F/S>2, <10% LRU and $|\delta_F| < 3\%/X_0$. R&D will continue to optimize yttrium doping in large size BaF₂:Y crystals for Mu2e-II.
 - ❑ SIC plans to reduce scattering centers by refining growth parameters.
 - ❑ BGRI plans to eliminate residual cerium contamination by purifying raw material.
 - ❑ Caltech plans to investigate radiation hardness of BaF₂:Y crystals.
- ❑ Effort is also needed to develop VUV photodetector, such as solar-blind SiPM, LAPPD or diamond-based photodetectors.

Acknowledgements: DOE HEP Award DE-SC001192